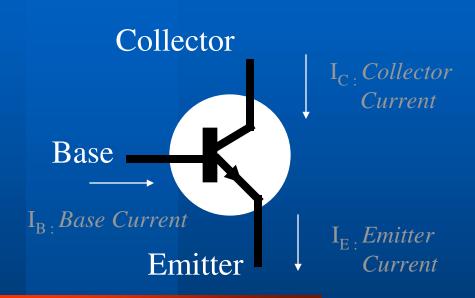
# Transistors



#### Review: What is a Transistor?



#### **NPN Transistor Rules:**

$$V_C > V_E$$
  
 $V_B = V_E + 0.6 \text{ Volts}$   
 $I_C = I_B * \beta$ 

$$I_E = I_C + I_B \Rightarrow$$
  
 $I_E = (1 + \beta) I_B$ 

#### **FOR MORE INFO...**

Relevant Books: Art of Electronics + Lab: Harowitz and Hill

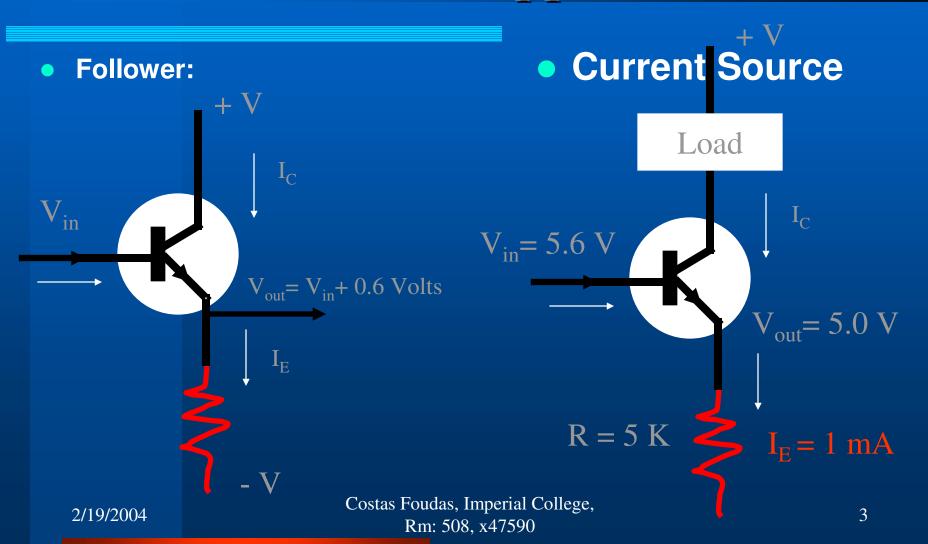
Electronic Circuits: E.C. Lowenberg, SCHAUM SERIES

Electric Circuits: J.A. EDMINISTER SCHAUM SERIES

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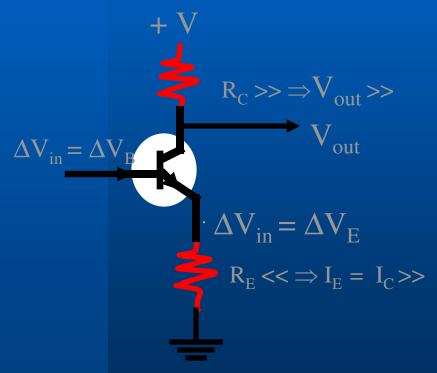
# Some Transistor Applications I



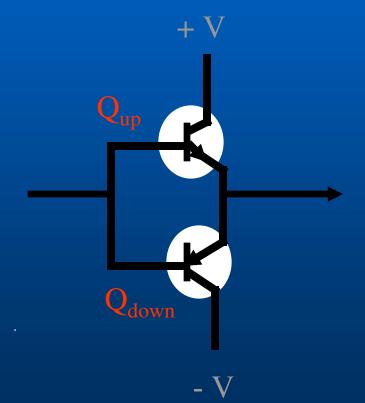


# Some Transistor Applications II

Common Emitter Amplifier :



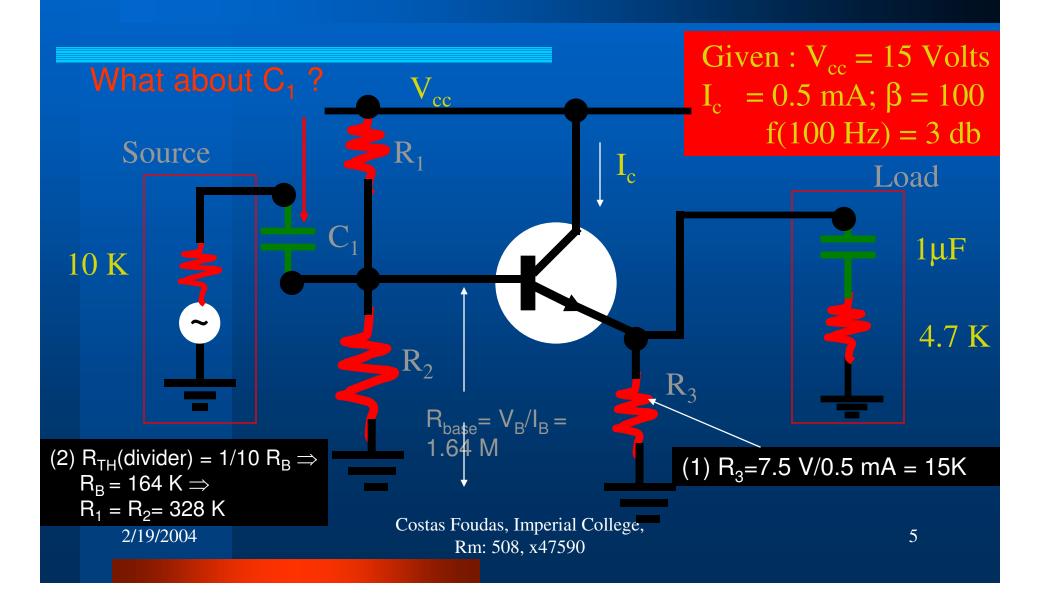
• Push-Pull:



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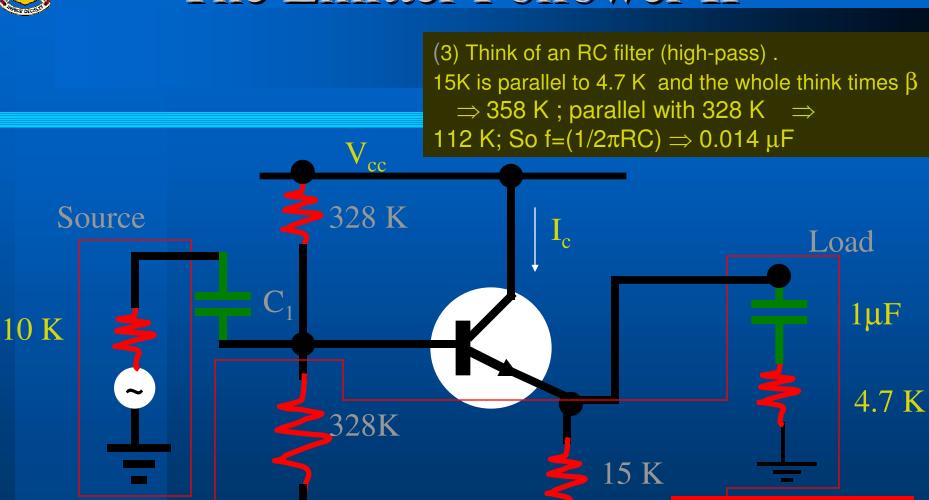


#### The Emitter Follower I





#### The Emitter Follower II

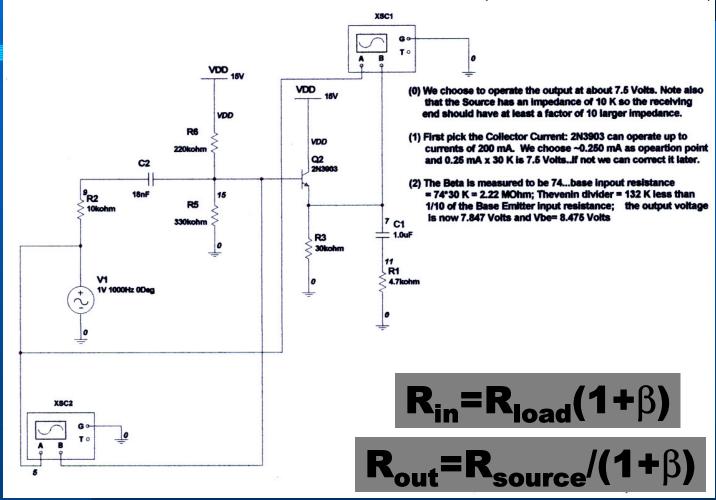


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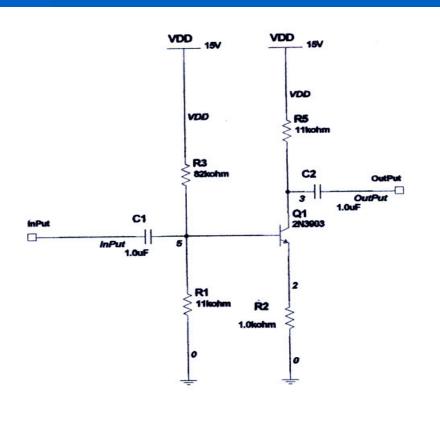


# Emitter Follower (a bit diff.)





### Common Emitter Amplifier



Gain = R5/R2

$$R_{out} = R_5$$



### Common Emitter Amplifier II

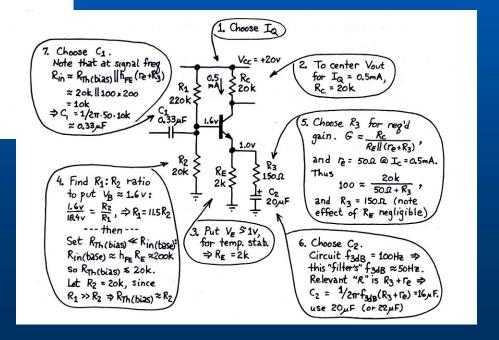
#### Problem: common emitter amp

Design a common-emitter amp to the following specs:

- V + = 20V
- $f_{3dB} = 100 \text{ Hz (approx.)}$
- gain = -100 at quiescent point.
- $I_C$  quiescent = 0.5 mA

#### Questions:

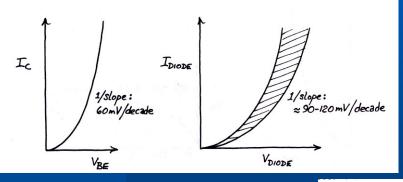
- What is the amp's gain—
  - when the output swings to about + 15v?
  - when the output swings to about + 5v?
- What is the amp's Z<sub>out?</sub>

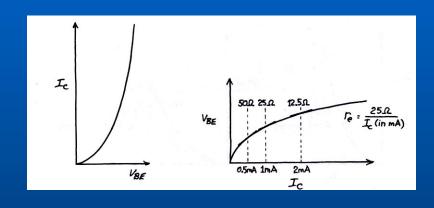




### The Ebers-Moll Model for BJT

Class 5: Tr II: Corrections to the first model: Ebers-Moll





Ebers-Moll

$$I_C = I_S(e^{V_{BE}/(kT/q)} - 1)$$

(grows fast with temperature; more on this later)

(negligible)

Ignoring the "-1" term, we can say simply that  $I_C$  grows exponentially with  $V_{\rm BE}$ .

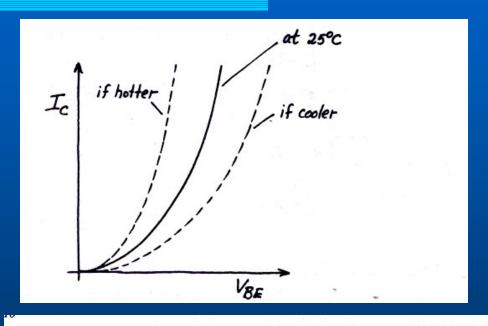
In addition, we might as well plug in the room-temperature value for that complicated expression "kT/q:" 25 mV. Then Ebers-Moll doesn't look so bad:

Ebers-Moll: (slightly simplified)

$$I_{\rm C} \approx I_{\rm S} \, {\rm e}^{V_{\rm BE}/25 {\rm mV}}$$



# Temperature Effects

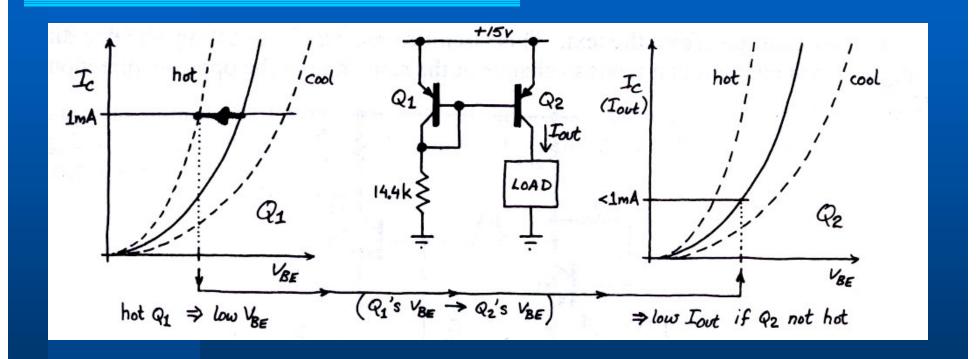


#### Temperature Effects: two equivalent formulations

- $I_{\rm C}$  grows at about 9%/°C, if you hold  $V_{\rm RE}$  constant.
- $V_{\rm BE}$  falls at 2mV/°C, if you hold  $I_{\rm C}$  constant (This is the text's formulation.)



# Temperature Effects and Current Mirrors



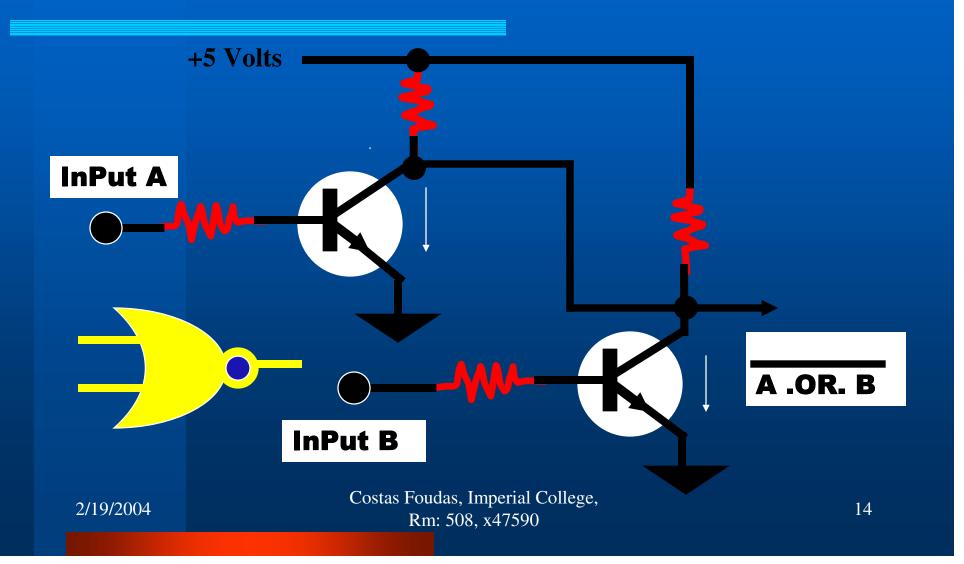


#### Exercises

- Make a Current Source using a transistor
- Make common emitter follower
- Make a Common Emitter Amplifier

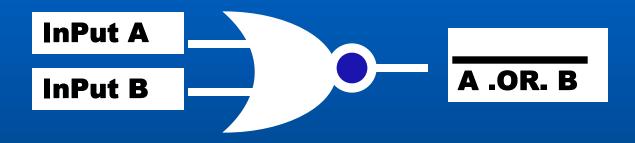


# Making Gates using Transistors I





### Making Gates using Transistors II



Here is what we have made

Α	A	OUT
1	0	0
1	1	0
0	1	0
0	0	1

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#### Exercise I

# **Design and construct an AND gate using transistors and resistors:**

**InPut A** 

**InPut B** 

A .AND. B

A A OUT

1 0 0

1 1 1

0 1 0

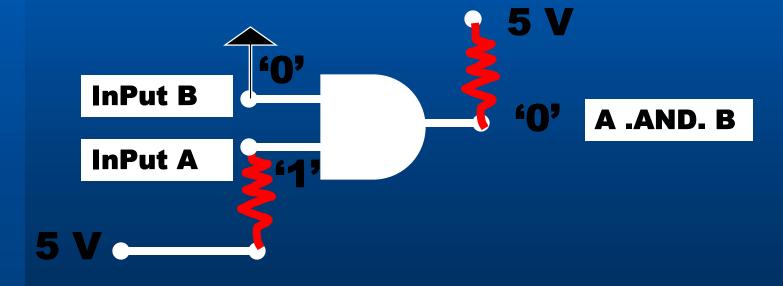
0 0

# The AND gate TRUTH table



#### Exercise I continued

Verify the truth table! You can set an input to '1' by connecting it to +5 V by a resistor of 1K and you set it to '0' by grounding it.

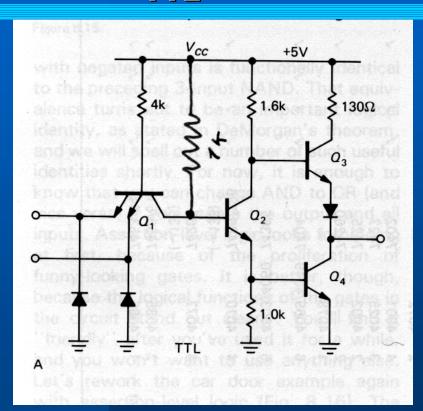


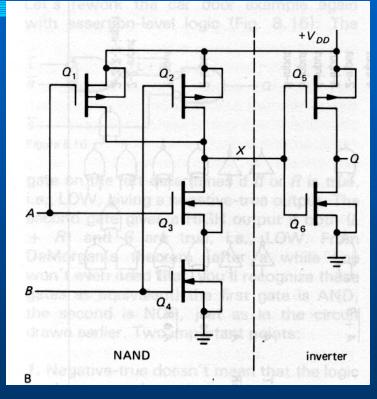
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#### **Answer (almost):**

**CMOS** TTL





Not quite because this is a NAND gate but we do know by now how to invert using a transistor Costas Foudas, Imperial College,

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### Important conclusion

You may understand by now that the inputs have no ability to set signals high or low. In contrast to this the outputs can drive signals to High or Low



#### Remember:

Inputs draw no current.  $1K\Omega$  resistors to +5 V can set inputs to high or they can be set low by connecting to ground.

Outputs can draw current and can force lines to low or high.